

WEST[Generate Collection](#)[Print](#)**Search Results - Record(s) 1 through 20 of 24 returned.**☐ 1. Document ID: US 6518077 B2

L2: Entry 1 of 24

File: USPT

Feb 11, 2003

US-PAT-NO: 6518077

DOCUMENT-IDENTIFIER: US 6518077 B2

TITLE: Method for making optoelectronic and microelectronic devices including cubic ZnMgO and/or CdMgO alloys

DATE-ISSUED: February 11, 2003

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Narayan; Jagdish	Raleigh	NC		
Sharma; Ajay Kumar	Hillsboro	OR		
Muth; John F.	Cary	NC		

US-CL-CURRENT: 438/22; 257/96, 438/20

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KWIC
Draw Desc	Image										

☐ 2. Document ID: US 6496260 B1

L2: Entry 2 of 24

File: USPT

Dec 17, 2002

US-PAT-NO: 6496260

DOCUMENT-IDENTIFIER: US 6496260 B1

TITLE: Vertical-beam photometer for determination of light absorption pathlength

DATE-ISSUED: December 17, 2002

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Hafeman; Dean G.	Hillsborough	CA		
Chow; Calvin Y.	Portola Valley	CA		

US-CL-CURRENT: 356/433; 356/436

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KWIC
Draw Desc	Image										

☐ 3. Document ID: US 6472276 B1

L2: Entry 3 of 24

File: USPT

Oct 29, 2002

US-PAT-NO: 6472276

DOCUMENT-IDENTIFIER: US 6472276 B1

**** See image for Certificate of Correction ****TITLE: Using silicate layers for composite semiconductor

DATE-ISSUED: October 29, 2002

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Hilt; Lyndee L.	Chandler	AZ		
Droopad; Ravindranath	Chandler	AZ		

US-CL-CURRENT: 438/285; 438/3, 438/602, 438/604

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KWIC
Draw Desc	Image										

☐ 4. Document ID: US 6462360 B1

L2: Entry 4 of 24

File: USPT

Oct 8, 2002

US-PAT-NO: 6462360

DOCUMENT-IDENTIFIER: US 6462360 B1

TITLE: Integrated gallium arsenide communications systems

DATE-ISSUED: October 8, 2002

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Higgins, Jr.; Robert J.	Plantation	FL		
Stengel; Robert E.	Ft. Lauderdale	FL		

US-CL-CURRENT: 257/189; 257/295, 438/285, 438/3, 438/602, 438/604

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KWIC
Draw Desc	Image										

☐ 5. Document ID: US 6441393 B2

L2: Entry 5 of 24

File: USPT

Aug 27, 2002

US-PAT-NO: 6441393

DOCUMENT-IDENTIFIER: US 6441393 B2

TITLE: Semiconductor devices with selectively doped III-V nitride layers

DATE-ISSUED: August 27, 2002

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Goetz; Werner	Palo Alto	CA		
Kern; R. Scott	San Jose	CA		

US-CL-CURRENT: 257/13; 257/79, 257/83, 257/87, 257/94, 257/E33.03

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

KVMC

☐ 6. Document ID: US 6427066 B1

L2: Entry 6 of 24

File: USPT

Jul 30, 2002

US-PAT-NO: 6427066

DOCUMENT-IDENTIFIER: US 6427066 B1

TITLE: Apparatus and method for effecting communications among a plurality of remote stations

DATE-ISSUED: July 30, 2002

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Grube; Gary W.	Barrington	IL		

US-CL-CURRENT: 455/73; 257/295, 257/347, 370/338, 438/2, 438/478, 438/488, 455/347, 455/556.1, 455/66.1, 455/81, 455/90.1

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

KVMC

☐ 7. Document ID: US 6423983 B1

L2: Entry 7 of 24

File: USPT

Jul 23, 2002

US-PAT-NO: 6423983

DOCUMENT-IDENTIFIER: US 6423983 B1

TITLE: Optoelectronic and microelectronic devices including cubic ZnMgO and/or CdMgO alloys

DATE-ISSUED: July 23, 2002

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Narayan; Jagdish	Raleigh	NC		
Sharma; Ajay Kumar	Hillsboro	OR		
Muth; John F.	Cary	NC		

US-CL-CURRENT: 257/96; 257/103, 257/E29.096, 257/E33.021

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

KVMC

☐ 8. Document ID: US 6404501 B1

L2: Entry 8 of 24

File: USPT

Jun 11, 2002

US-PAT-NO: 6404501

DOCUMENT-IDENTIFIER: US 6404501 B1

TITLE: Determination of light absorption pathlength in a vertical-beam photometer

DATE-ISSUED: June 11, 2002

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Hafeman; Dean G.	Hillsborough	CA		
Chow; Calvin Y.	Portola Valley	CA		

US-CL-CURRENT: 356/436; 356/440

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

KWC

☐ 9. Document ID: US 6339472 B1

L2: Entry 9 of 24

File: USPT

Jan 15, 2002

US-PAT-NO: 6339472

DOCUMENT-IDENTIFIER: US 6339472 B1

TITLE: Determination of light absorption pathlength in a vertical-beam photometer

DATE-ISSUED: January 15, 2002

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Hafeman; Dean G.	Hillsborough	CA	94010	
Chow; Calvin T.	Portola Valley	CA	94028	

US-CL-CURRENT: 356/433; 356/436

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

KWC

☐ 10. Document ID: US 6320662 B1

L2: Entry 10 of 24

File: USPT

Nov 20, 2001

US-PAT-NO: 6320662

DOCUMENT-IDENTIFIER: US 6320662 B1

TITLE: Determination of light absorption pathlength in a vertical-beam photometer

DATE-ISSUED: November 20, 2001

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Hafeman; Dean G.	Hillsborough	CA		
Chow; Calvin T.	Portola Valley	CA		

US-CL-CURRENT: 356/436; 356/440

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	KMIC
Drawn Desc	Image									

☐ 11. Document ID: US 6265726 B1

L2: Entry 11 of 24

File: USPT

Jul 24, 2001

US-PAT-NO: 6265726

DOCUMENT-IDENTIFIER: US 6265726 B1

TITLE: Light-emitting aluminum gallium indium nitride compound semiconductor device having an improved luminous intensity

DATE-ISSUED: July 24, 2001

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Manabe; Katsuhide	Aichi-ken			JP
Kato; Hisaki	Aichi-ken			JP
Sassa; Michinari	Aichi-ken			JP
Yamazaki; Shiro	Aichi-ken			JP
Asai; Makoto	Aichi-ken			JP
Shibata; Naoki	Aichi-ken			JP
Koike; Masayoshi	Nakashima-gun			JP

US-CL-CURRENT: 257/13; 257/101, 257/102, 257/103, 257/87, 257/94, 257/E33.03, 257/E33.049, 257/E33.065

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	KMIC
Drawn Desc	Image									

☐ 12. Document ID: US 6188476 B1

L2: Entry 12 of 24

File: USPT

Feb 13, 2001

US-PAT-NO: 6188476

DOCUMENT-IDENTIFIER: US 6188476 B1

TITLE: Determination of light absorption pathlength in a vertical-beam photometer

DATE-ISSUED: February 13, 2001

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Hafeman; Dean G.	Hillsborough	CA		
Chow; Calvin T.	Portola Valley	CA		

US-CL-CURRENT: 356/343; 356/436

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
Draw Desc	Image								

KMC

☐ 13. Document ID: US 6069367 A

L2: Entry 13 of 24

File: USPT

May 30, 2000

US-PAT-NO: 6069367

DOCUMENT-IDENTIFIER: US 6069367 A

TITLE: Semiconductor element and semiconductor light-emitting and semiconductor photoreceptor devices

DATE-ISSUED: May 30, 2000

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Tomiya; Shigetaka	Kanagawa			JP
Kijima; Satoru	Kanagawa			JP
Okuyama; Hiroyuki	Kanagawa			JP
Taniguchi; Satoshi	Kanagawa			JP
Tsukamoto; Hironori	Kanagawa			JP

US-CL-CURRENT: 257/22; 257/184, 257/201, 257/21, 257/96, 257/97, 257/E29.078,
257/E33.008, 257/E33.063

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
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KMC

☐ 14. Document ID: US 6005258 A

L2: Entry 14 of 24

File: USPT

Dec 21, 1999

US-PAT-NO: 6005258

DOCUMENT-IDENTIFIER: US 6005258 A

** See image for Certificate of Correction **

TITLE: Light-emitting semiconductor device using group III Nitrogen compound having emission layer doped with donor and acceptor impurities

DATE-ISSUED: December 21, 1999

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Manabe; Katsuhide	Nakashima-gun			JP
Kato; Hisaki	Nakashima-gun			JP
Sassa; Michinari	Nakashima-gun			JP
Yamazaki; Shiro	Nakashima-gun			JP
Asai; Makoto	Nakashima-gun			JP
Shibata; Naoki	Nakashima-gun			JP
Koike; Masayoshi	Nakashima-gun			JP

US-CL-CURRENT: 257/13; 257/101, 257/102, 257/103, 257/87, 257/94, 257/E33.03,
257/E33.049, 257/E33.065

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
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☐ 15. Document ID: US 5959738 A

L2: Entry 15 of 24

File: USPT

Sep 28, 1999

US-PAT-NO: 5959738

DOCUMENT-IDENTIFIER: US 5959738 A

TITLE: Determination of light absorption pathlength in a vertical-beam photometer

DATE-ISSUED: September 28, 1999

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Hafeman; Dean G.	Hillsborough	CA		
Chow; Calvin T.	Portola Valley	CA		

US-CL-CURRENT: 356/440; 250/339.05, 250/339.12, 250/373, 356/319, 356/416, 356/442

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
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☐ 16. Document ID: US 5883564 A

L2: Entry 16 of 24

File: USPT

Mar 16, 1999

US-PAT-NO: 5883564

DOCUMENT-IDENTIFIER: US 5883564 A

TITLE: Magnetic field sensor having high mobility thin indium antimonide active layer on thin aluminum indium antimonide buffer layer

DATE-ISSUED: March 16, 1999

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Partin; Dale Lee	Ray	MI		

US-CL-CURRENT: 338/32R; 257/E43.003, 257/E43.004, 338/32H

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
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☐ 17. Document ID: US 5753939 A

L2: Entry 17 of 24

File: USPT

May 19, 1998

US-PAT-NO: 5753939

DOCUMENT-IDENTIFIER: US 5753939 A

** See image for Certificate of Correction **

TITLE: Light-emitting semiconductor device using a Group III nitride compound and having a contact layer upon which an electrode is formed

DATE-ISSUED: May 19, 1998

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Sassa; Michinari	Ama-gun, Aichi-ken, 490-11			JP
Shibata; Naoki	Bisai-shi, Aichi-ken, 494			JP
Asami; Shinya	Nishikasugai-gun, Aichi-ken, 452			JP
Koike; Masayoshi	Ichinomiya-shi, Aichi-ken, 491			JP
Umezaki; Junichi	Inuyama-shi, Aichi-ken, 484			JP
Kozawa; Takahiro	Owariasahi-shi, Aichi-ken, 488			JP

US-CL-CURRENT: 257/94; 257/101, 257/102, 257/103, 257/96, 257/E33.028, 257/E33.03, 257/E33.065

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
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KWC

☐ 18. Document ID: US 5652438 A

L2: Entry 18 of 24

File: USPT

Jul 29, 1997

US-PAT-NO: 5652438

DOCUMENT-IDENTIFIER: US 5652438 A

TITLE: Light-emitting semiconductor device using group III nitride compound

DATE-ISSUED: July 29, 1997

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Sassa; Michinari	Aichi-ken			JP
Tamaki; Makoto	Aichi-ken			JP
Koike; Masayoshi	Aichi-ken			JP
Shibata; Naoki	Aichi-ken			JP
Yamada; Masami	Aichi-ken			JP
Oshio; Takahide	Aichi-ken			JP

US-CL-CURRENT: 257/94; 257/103, 257/95, 257/96, 257/97, 257/99, 257/E33.028, 257/E33.03, 257/E33.065

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
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KWC

☐ 19. Document ID: US 5371409 A

L2: Entry 19 of 24

File: USPT

Dec 6, 1994

US-PAT-NO: 5371409

DOCUMENT-IDENTIFIER: US 5371409 A

TITLE: Wide bandgap semiconductor light emitters

DATE-ISSUED: December 6, 1994

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
McCaldin; James O.	San Diego	CA		
McGill; Thomas C.	Pasadena	CA		
Phillips; Mark C.	Pasadena	CA		

US-CL-CURRENT: 257/741; 257/191, 257/201, 257/E33.021, 257/E33.05

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
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☐ 20. Document ID: US 5306915 A

L2: Entry 20 of 24

File: USPT

Apr 26, 1994

US-PAT-NO: 5306915

DOCUMENT-IDENTIFIER: US 5306915 A

TITLE: Infrared detectors

DATE-ISSUED: April 26, 1994

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Matthews; Brian E.	Southampton			GB3

US-CL-CURRENT: 250/370.13; 250/332, 250/338.4, 250/349, 250/370.08, 257/E31.038,
257/E31.128

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments
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Semiconductor and LED and (buffer same cadmium)	24

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